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APPLICATION NO. FILING DATE		LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/681,400	400 10/08/2003		Leland Swanson	TI-35902	7441		
23494	7590	03/21/2005		EXAM	EXAMINER		
		ENTS INCORPOR	EVERHART	EVERHART, CARIDAD			
P O BOX 655474, M/S 3999 DALLAS, TX 75265				ART UNIT	PAPER NUMBER		
				2829			

DATE MAILED: 03/21/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applica	ition No.	Applicant(s)				
			,400	SWANSON ET AL.	M			
	Office Action Summary	Examin	er	Art Unit				
		Caridad	M. Everhart	2825				
Period fo	The MAILING DATE of this commu or Reply	nication appears on t	he cover sheet with the d	correspondence address				
THE I - Exter after - If the - If NO - Failu Any r	ORTENED STATUTORY PERIOD F MAILING DATE OF THIS COMMUN sions of time may be available under the provision SIX (6) MONTHS from the mailing date of this com period for reply specified above is less than thirty (period for reply is specified above, the maximum s re to reply within the set or extended period for repl reply received by the Office later than three months and patent term adjustment. See 37 CFR 1.704(b).	IICATION. s of 37 CFR 1.136(a). In no munication. 30) days, a reply within the s tatutory period will apply and y will, by statute, cause the a	event, however, may a reply be tir tatutory minimum of thirty (30) day will expire SIX (6) MONTHS from pplication to become ABANDONE	nely filed /s will be considered timely. In the mailing date of this communic ED (35 U.S.C. § 133).	cation.			
Status								
1)	Responsive to communication(s) fil	ed on						
2a) <u></u> ☐	This action is FINAL .	2b)⊠ This action is	non-final.					
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Dispositi	on of Claims							
5)⊠ 6)⊠ 7)⊠	Claim(s) <u>1-29</u> is/are pending in the 4a) Of the above claim(s) is/a Claim(s) <u>13-19</u> is/are allowed. Claim(s) <u>1,8,20,24 and 29</u> is/are reclaim(s) <u>2-7,9-12,21-23 and 25-28</u> Claim(s) are subject to restrict	are withdrawn from o ected. is/are objected to.						
Applicati	on Papers							
9)[The specification is objected to by the	ne Examiner.						
10)	The drawing(s) filed on is/are	e: a)□ accepted or	b)□ objected to by the	Examiner.				
	Applicant may not request that any object	ection to the drawing(s) be held in abeyance. Se	e 37 CFR 1.85(a).				
11)	Replacement drawing sheet(s) includin The oath or declaration is objected t	•	• ,	<u>-</u>	• •			
Priority u	ınder 35 U.S.C. § 119							
a)[Acknowledgment is made of a claim All b) Some * c) None of: 1. Certified copies of the priority 2. Certified copies of the priority 3. Copies of the certified copies application from the Internationsee the attached detailed Office actions	documents have be documents have be of the priority documents Bureau (PCT R	een received. een received in Applicat ments have been receive ule 17.2(a)).	ion No ed in this National Stage	9			
2) Notic 3) Inform	t(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (i nation Disclosure Statement(s) (PTO-1449 o r No(s)/Mail Date <u>10-8-2003</u> .		4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal F 6) Other:					

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Specification

The abstract of the disclosure is objected to because of the including of the recitation "comprising", as the Abstract should not include legal terms such as used in the claims. Correction is required. See MPEP § 608.01(b).

Claim Objections

Claim 28 objected to because of the following informalities: Claim 28 recites "further comprising" twice. Appropriate correction is required.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 8, 20, 24, and 29 are rejected under 35 U.S.C. 102(e) as being anticipated by Grover, et al. (US 2003/0022474A1).

Grover, et al disclose a Schottky device and method of forming(first two lines of paragraph 0019) in which the substrate is of a conductivity type(paragraph 0039). There is also disclosed a guard ring(paragraph 0078) structure which includes a gate of a different conductivity type(paragraph 0055). The gate has an insulation layer over which the gate is formed, which is interpreted as a gate dielectric(paragraph 0055). In Fig. 11 it can be seen that there are barrier regions 15s(described in the abstract as

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guard regions, but because of their doping these are interpreted as barrier regions). The layer 33a is a metal layer (paragraph 0065, as is the layer 33(paragraph 0065). Layer 33a is silicide (paragraph 0040). The layer 33a may have a metallurgical barrier such as TiN on it (paragraph 0066). It is disclosed in the Abstract that the Schottky barrier is self-aligned with the barrier regions 15s(described as guard regions), and it can also be seen in Fig. 2 that the Schottky barrier 80 is self aligned with 15s(paragraph 0042). There is also a depletion region under the gate dielectric and the barrier region(paragraph 0081 and Fig. 1, feature 14). The limitation "over the substrate layer" is interpreted to include that the substrate layer may have trenches therein as disclosed by Grover, et al, and then layers formed over the trenches are interpreted to satisfy the limitation "over the substrate layer". The providing of the guard ring structure is a method of mitigating perimeter edge effects of a Schottky diode, as Grover, et al include Schottky diode (end of paragraph 0001) as the devices which can benefit from the structure(benefits are implied in second half of paragraph 0004), which would incude perimeter edge effects, as this is implied by the providing of a guard ring.

Allowable Subject Matter

Claims 13-19 are allowed.

Claims 207,9-12,21-23,25-28 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Caridad M. Everhart whose telephone number is 571-

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272-1892. The examiner can normally be reached on Monday through Fridays 7:30-4:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, B. Baumeister can be reached on 571-272-1722. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

C. Everhart 3-17-2005